

Bi₂O₂Se纳米带的气-液-固生长与高性能晶体管的构筑

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Vapor-Liquid-Solid Growth of Bi₂O₂Se Nanoribbons for High-Performance Transistors

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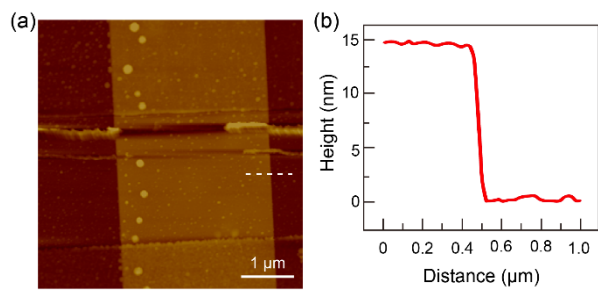


Fig. S1 The corresponding AFM images and height profiles of FET transistor of the Fig. 4d in the main text.